

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18
Stylesheet Version v18.0

Title of Invention

MODIFIED TRANSFER FUNCTION DEPOSITION BAFFLES AND HIGH DENSITY PLASMA IGNITION THEREWITH IN SEMICONDUCTOR PROCESSING

Application Number:

10/080496

- 1 (2101) (1101) 1401 (1101) (1101) (1101) (1101) (1101) (1101) (1101) (1101) (1101) (1101)

Confirmation Number:

8492

First Named Applicant:

Jozef Brcka

Attorney Docket Number: TAZ213

RECEIVED

Art Unit:

1763

AUG 1 5 7003

Examiner: Search string: Luz L. (6287435).pn.

GROUP 1700

<u>Certification:</u> This Information Disclosure Statement was submitted under the following conditions, which satisfies the requirement under 37 CFR 1.97(e). The filer certified:

That each item of information contained in the information disclosure statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the information disclosure statement.

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

2/21/05

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
	1	6287435	2001-09-11	Drewery et al.	T	\equiv	

Signature

Examiner Name	Date
Xeliaidio	12/23/05

ALAM 3/21/05